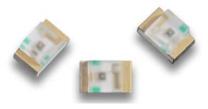


### AP2012SF4C-P22

2.0 x 1.25 mm Infrared Emitting Diode



### DESCRIPTION

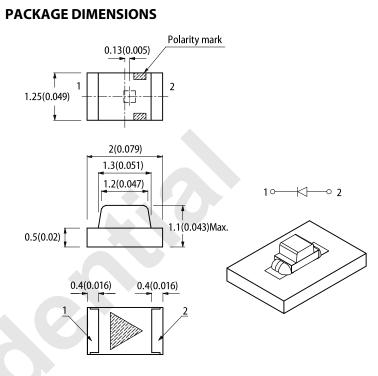
 SF4 Made with Gallium Aluminum Arsenide Infrared Emitting diodes

#### **FEATURES**

- 2.0 mm x 1.25 mm SMD LED, 1.1 mm thickness
- · Mechanically and spectrally matched to the phototransistor
- Package : 2000 pcs / reel
- Moisture sensitivity level: 3
- RoHS compliant

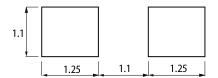
#### **APPLICATIONS**

- · Infrared Illumination for cameras
- Machine vision systems
- Surveillance systems
- · Industrial electronics
- IR data transmission
- Remote control



#### **RECOMMENDED SOLDERING PATTERN**

(units : mm; tolerance :  $\pm 0.1$ )



Notes:

1. All dimensions are in millimeters (inches).

Tolerance is ±0.1(0.004") unless otherwise noted.
 The specifications, characteristics and technical data described in the datasheet are subject to

change without prior notice. 4. The device has a single mounting surface. The device must be mounted according to the specifications.

#### **SELECTION GUIDE**

Part Number	Emitting Color (Material)	Lens Type	Po (mW/sr) @ 20mA <sup>[2]</sup>		Viewing Angle <sup>[1]</sup>	
			Min.	Тур.	201/2	
AP2012SF4C-P22	Infrared (GaAIAs)	Water Clear	0.8	1.5	160°	

Notes: 1. 01/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value. 2. Radiant Intensity / luminous flux: +/-15%. 3. Radiant intensity value is traceable to CIE127-2007 standards.

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#### ELECTRICAL / OPTICAL CHARACTERISTICS at T<sub>A</sub>=25°C

Devemeter	Symbol	Emitting Color	Value		11-14
Parameter			Тур.	Max.	Unit
Wavelength at Peak Emission $I_F$ = 20mA	$\lambda_{peak}$	Infrared	880	-	nm
Spectral Bandwidth at 50% $\Phi$ REL MAX $I_F$ = 20mA	Δλ	Infrared	50	-	nm
Capacitance	С	Infrared	90	-	pF
Forward Voltage $I_F$ = 20mA	V <sub>F</sub> <sup>[1]</sup>	Infrared	1.3	1.6	V
Reverse Current (V <sub>R</sub> = 5V)	I <sub>R</sub>	Infrared		10	μA
Temperature Coefficient of Wavelength $I_F$ = 20mA, -10°C $\leq T \leq 85^\circ C$	TC <sub>λ</sub>	Infrared	0.3	-	nm/°C
Temperature Coefficient of $~V_F$ $I_F$ = 20mA, -10°C $\leq T \leq 85^\circ C$	TCv	Infrared	-1.3	-	mV/°C

Notes

Forward voltage: ±0.1V.
 Wavelength value is traceable to CIE127-2007 standards.
 Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

Parameter	Symbol	Value	Unit			
Power Dissipation	PD	85	mW			
Reverse Voltage	V <sub>R</sub>	5	V			
Junction Temperature	Tj	125	°C			
Operating Temperature	T <sub>op</sub>	-40 to +85	°C			
Storage Temperature	T <sub>stg</sub>	-40 to +85	°C			
DC Forward Current	I <sub>F</sub>	50	mA			
Peak Forward Current	۱ <sub>FM</sub> <sup>[1]</sup>	1200	mA			
Electrostatic Discharge Threshold (HBM)	-	8000	V			
Thermal Resistance (Junction / Ambient)	R <sub>th JA</sub> <sup>[2]</sup>	320	°C/W			
Thermal Resistance (Junction / Solder point)	R <sub>th JS</sub> <sup>[2]</sup>	240	°C/W			

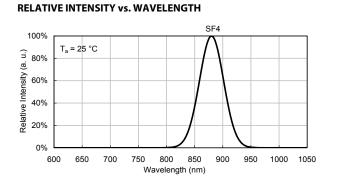
### ABSOLUTE MAXIMUM RATINGS at T<sub>A</sub>=25°C

Notes:

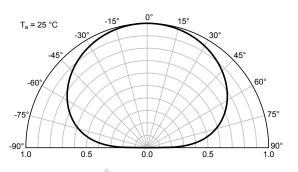
Notes: 1. 1/100 Duty Cycle, 10µs Pulse Width. 2. Rth JA, Rth JS Results from mounting on PC board FR4 (pad size ≥ 16 mm<sup>2</sup> per pad). 3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

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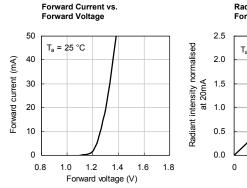
#### **TECHNICAL DATA**

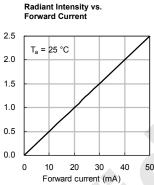


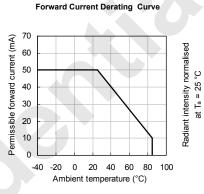
#### SPATIAL DISTRIBUTION



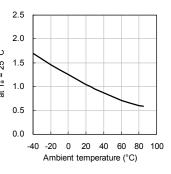
#### **INFRARED**



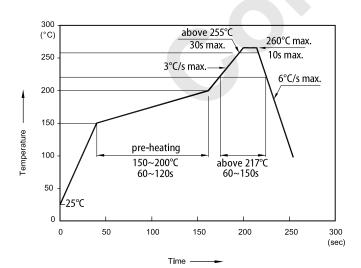




## Radiant Intensity vs. Ambient Temperature



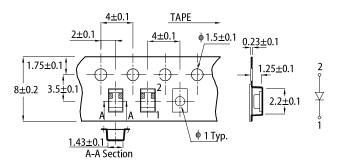
#### **REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS**



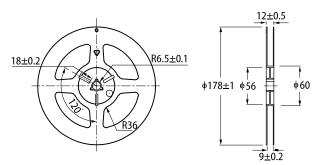
Notes 1. Don't cause stress to the LEDs while it is exposed to high temperature.

- The maximum number of reflow soldering passes is 2 times.
  Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

#### TAPE SPECIFICATIONS (units : mm)



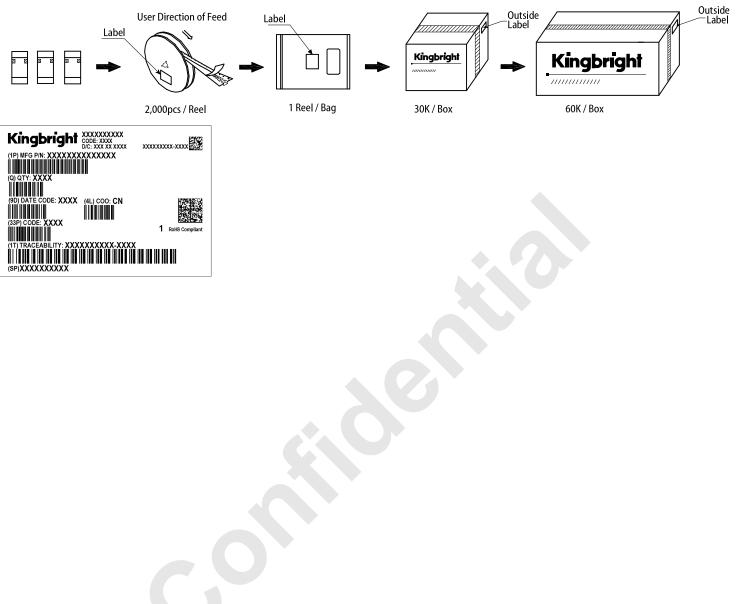
#### REEL DIMENSION (units : mm)



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# AP2012SF4C-P22

#### **PACKING & LABEL SPECIFICATIONS**



#### **PRECAUTIONARY NOTES**

- 1. The information included in this document reflects representative usage scenarios and is intended for technical reference only.
- 2. The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.
  The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening.
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  All design applications should refer to Kingbright application notes available at https://www.KingbrightUSA.com/ApplicationNotes

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